

# 74HC4051-Q100; 74HCT4051-Q100

## 8-channel analog multiplexer/demultiplexer

Rev. 2 — 8 October 2012

Product data sheet

### 1. General description

The 74HC4051-Q100; 74HCT4051-Q100 is a high-speed Si-gate CMOS device and is pin compatible with Low-power Schottky TTL (LSTTL). The device is specified in compliance with JEDEC standard no. 7A.

The 74HC4051-Q100; 74HCT4051-Q100 is an 8-channel analog multiplexer/demultiplexer with three digital select inputs (S0 to S2), an active-LOW enable input ( $\overline{E}$ ), eight independent inputs/outputs (Y0 to Y7) and a common input/output (Z). With  $\overline{E}$  LOW, one of the eight switches is selected (low impedance ON-state) by S0 to S2. With  $\overline{E}$  HIGH, all switches are in the high-impedance OFF-state, independent of S0 to S2.

$V_{CC}$  and GND are the supply voltage pins for the digital control inputs (S0 to S2, and  $\overline{E}$ ). The  $V_{CC}$  to GND ranges are 2.0 V to 10.0 V for 74HC4051-Q100 and 4.5 V to 5.5 V for 74HCT4051-Q100. The analog inputs/outputs (Y0 to Y7, and Z) can swing between  $V_{CC}$  as a positive limit and  $V_{EE}$  as a negative limit.  $V_{CC} - V_{EE}$  may not exceed 10.0 V. For operation as a digital multiplexer/demultiplexer,  $V_{EE}$  is connected to GND (typically ground).

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

### 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - ◆ Specified from  $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$  and from  $-40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$
- Wide analog input voltage range from  $-5\text{ V}$  to  $+5\text{ V}$
- Low ON resistance:
  - ◆  $80\ \Omega$  (typical) at  $V_{CC} - V_{EE} = 4.5\text{ V}$
  - ◆  $70\ \Omega$  (typical) at  $V_{CC} - V_{EE} = 6.0\text{ V}$
  - ◆  $60\ \Omega$  (typical) at  $V_{CC} - V_{EE} = 9.0\text{ V}$
- Logic level translation: to enable 5 V logic to communicate with  $\pm 5\text{ V}$  analog signals
- Typical 'break before make' built-in
- ESD protection:
  - ◆ MIL-STD-883, method 3015 exceeds 2000 V
  - ◆ HBM JESD22-A114F exceeds 2000 V
  - ◆ MM JESD22-A115-A exceeds 200 V ( $C = 200\text{ pf}$ ,  $R = 0\ \Omega$ )
  - ◆ CDM AEC-Q100-011 revision B exceeds 1000 V
- Multiple package options



### 3. Applications

- Analog multiplexing and demultiplexing
- Digital multiplexing and demultiplexing
- Signal gating

### 4. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74HC4051D-Q100 74HCT4051D-Q100	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74HC4051PW-Q100 74HCT4051PW-Q100	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1
74HC4051BQ-Q100 74HCT4051BQ-Q100	–40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 × 3.5 × 0.85 mm	SOT763-1

5. Functional diagram

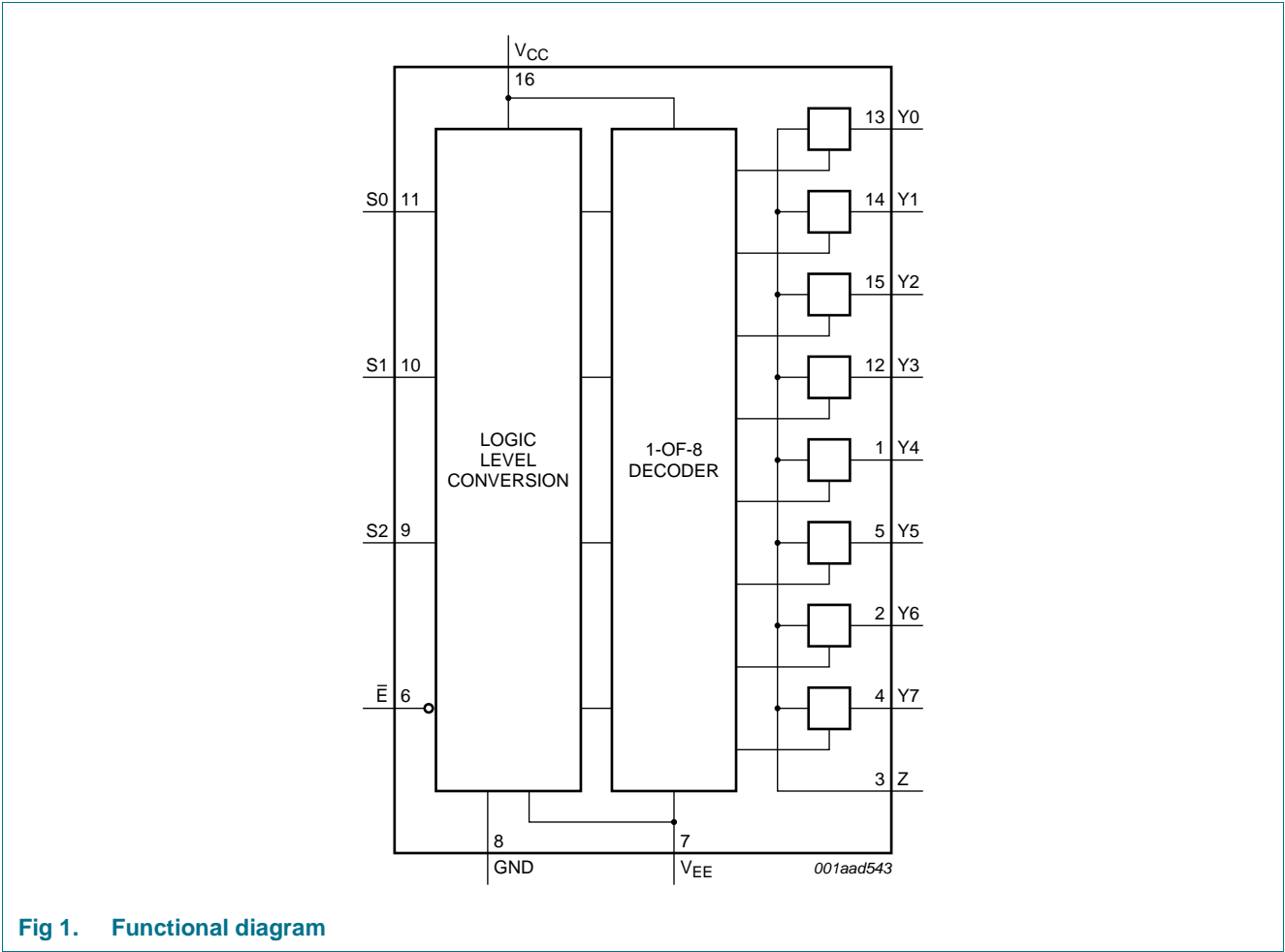


Fig 1. Functional diagram

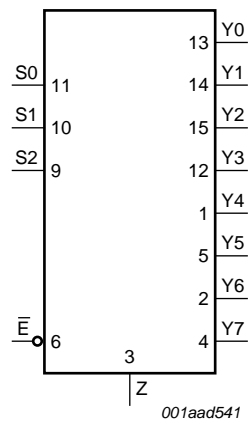


Fig 2. Logic symbol

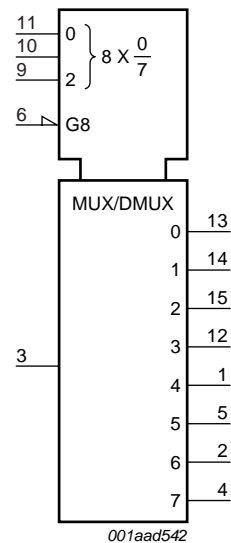


Fig 3. IEC logic symbol

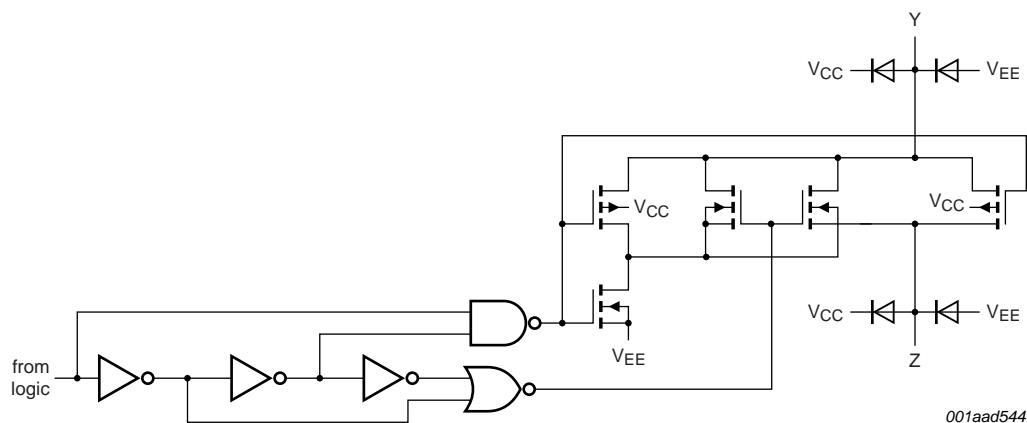
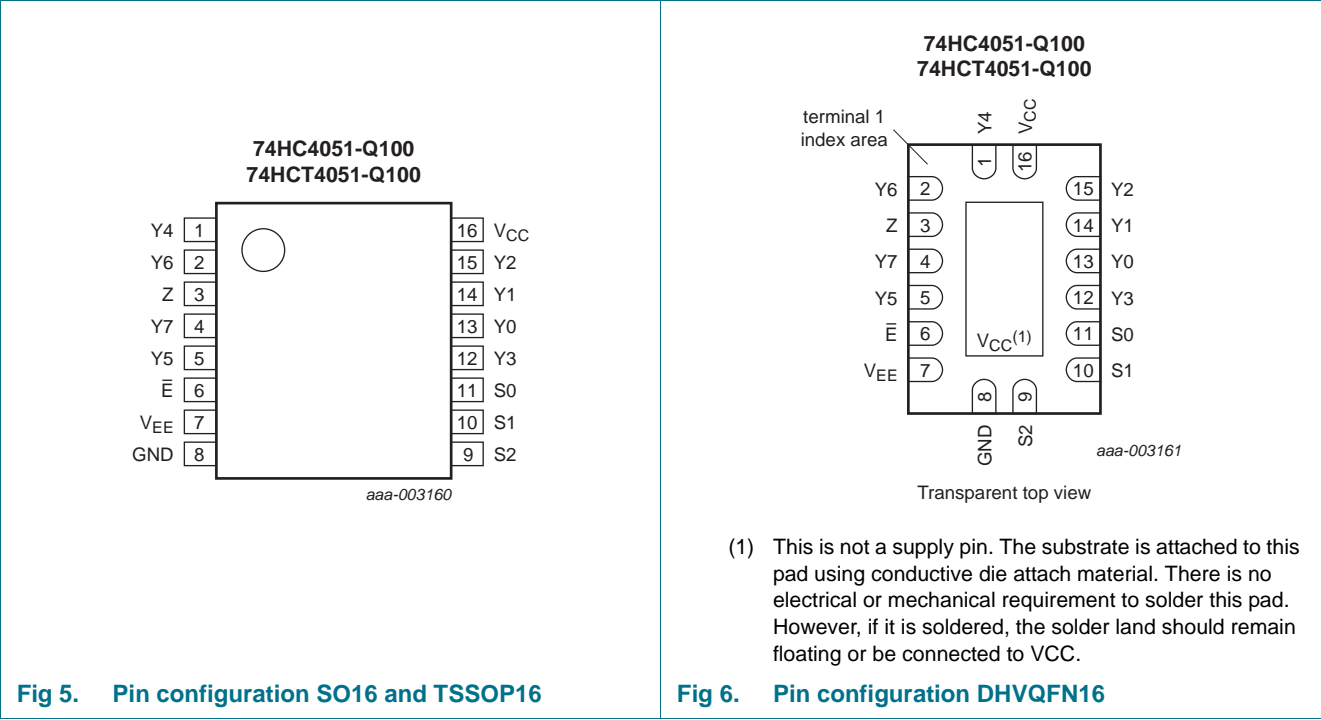


Fig 4. Schematic diagram (one switch)

6. Pinning information

6.1 Pinning



6.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
$\overline{E}$	6	enable input (active LOW)
$V_{EE}$	7	supply voltage
GND	8	ground supply voltage
S0, S1, S2	11, 10, 9	select input
Y0, Y1, Y2, Y3, Y4, Y5, Y6, Y7	13, 14, 15, 12, 1, 5, 2, 4	independent input or output
Z	3	common output or input
$V_{CC}$	16	supply voltage

## 7. Functional description

### 7.1 Function table

Table 3. Function table<sup>[1]</sup>

Input				Channel ON
$\overline{E}$	S2	S1	S0	
L	L	L	L	Y0 to Z
L	L	L	H	Y1 to Z
L	L	H	L	Y2 to Z
L	L	H	H	Y3 to Z
L	H	L	L	Y4 to Z
L	H	L	H	Y5 to Z
L	H	H	L	Y6 to Z
L	H	H	H	Y7 to Z
H	X	X	X	switches off

- [1] H = HIGH voltage level;  
L = LOW voltage level;  
X = don't care.

## 8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to  $V_{SS} = 0$  V (ground).

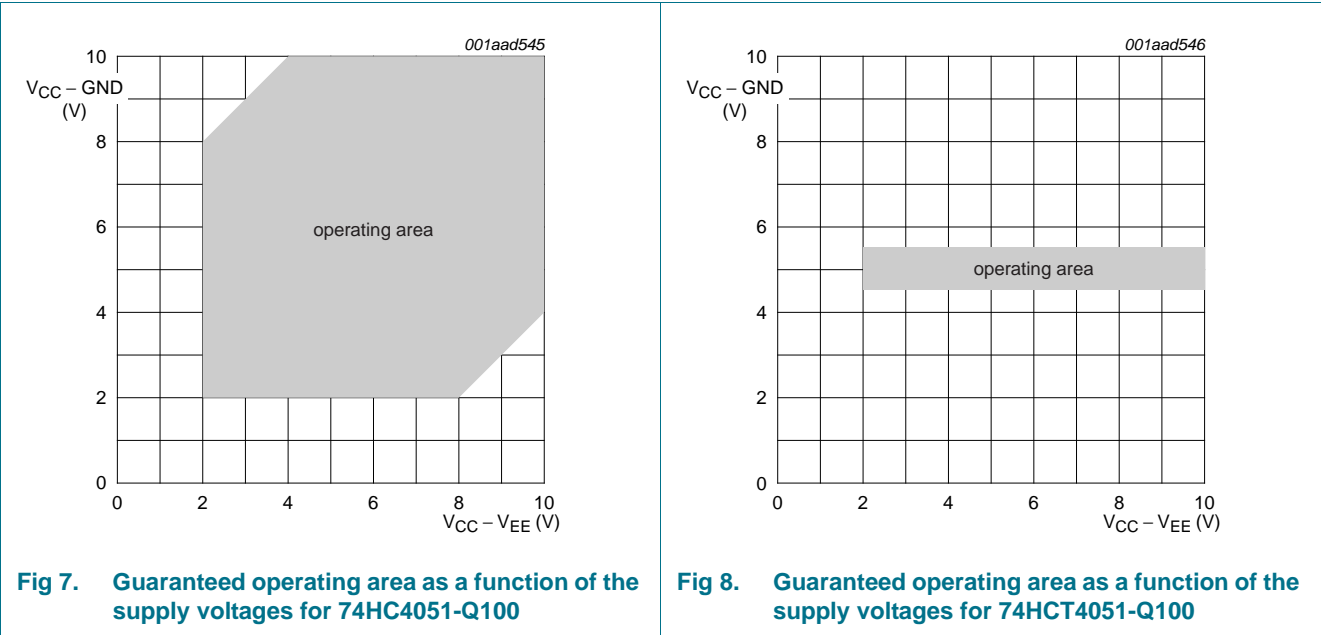
Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		<sup>[1]</sup> -0.5	+11.0	V
$I_{IK}$	input clamping current	$V_I < -0.5$ V or $V_I > V_{CC} + 0.5$ V	-	$\pm 20$	mA
$I_{SK}$	switch clamping current	$V_{SW} < -0.5$ V or $V_{SW} > V_{CC} + 0.5$ V	-	$\pm 20$	mA
$I_{SW}$	switch current	$-0.5$ V $< V_{SW} < V_{CC} + 0.5$ V	-	$\pm 25$	mA
$I_{EE}$	supply current		-	$\pm 20$	mA
$I_{CC}$	supply current		-	50	mA
$I_{GND}$	ground current		-	-50	mA
$T_{stg}$	storage temperature		-65	+150	°C
$P_{tot}$	total power dissipation		<sup>[2]</sup> -	500	mW
P	power dissipation	per switch	-	100	mW

- [1] To avoid drawing  $V_{CC}$  current out of terminal Z, when switch current flows into terminals  $Y_n$ , the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no  $V_{CC}$  current will flow out of terminals  $Y_n$ , and in this case there is no limit for the voltage drop across the switch, but the voltages at  $Y_n$  and Z may not exceed  $V_{CC}$  or  $V_{EE}$ .
- [2] For SO16 packages: above 70 °C the value of  $P_{tot}$  derates linearly with 8 mW/K.  
For TSSOP16 package: above 60 °C the value of  $P_{tot}$  derates linearly with 5.5 mW/K.  
For DHVQFN16 packages: above 60 °C the value of  $P_{tot}$  derates linearly with 4.5 mW/K.

9. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	74HC4051-Q100			74HCT4051-Q100			Unit
			Min	Typ	Max	Min	Typ	Max	
V <sub>CC</sub>	supply voltage	see <a href="#">Figure 7</a> and <a href="#">Figure 8</a>							
		V <sub>CC</sub> – GND	2.0	5.0	10.0	4.5	5.0	5.5	V
		V <sub>CC</sub> – V <sub>EE</sub>	2.0	5.0	10.0	2.0	5.0	10.0	V
V <sub>I</sub>	input voltage		GND	-	V <sub>CC</sub>	GND	-	V <sub>CC</sub>	V
V <sub>SW</sub>	switch voltage		V <sub>EE</sub>	-	V <sub>CC</sub>	V <sub>EE</sub>	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		–40	+25	+125	–40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 2.0 V	-	-	625	-	-	-	ns/V
		V <sub>CC</sub> = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V <sub>CC</sub> = 6.0 V	-	-	83	-	-	-	ns/V
		V <sub>CC</sub> = 10.0 V	-	-	31	-	-	-	ns/V



## 10. Static characteristics

**Table 6.**  $R_{ON}$  resistance per switch for 74HC4051-Q100 and 74HCT4051-Q100

$V_I = V_{IH}$  or  $V_{IL}$ ; for test circuit see [Figure 9](#).

$V_{is}$  is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

$V_{os}$  is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

For 74HC4051-Q100:  $V_{CC} - GND$  or  $V_{CC} - V_{EE} = 2.0\text{ V}$ ,  $4.5\text{ V}$ ,  $6.0\text{ V}$  and  $9.0\text{ V}$ .

For 74HCT4051-Q100:  $V_{CC} - GND = 4.5\text{ V}$  and  $5.5\text{ V}$ ,  $V_{CC} - V_{EE} = 2.0\text{ V}$ ,  $4.5\text{ V}$ ,  $6.0\text{ V}$  and  $9.0\text{ V}$ .

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b><math>T_{amb} = 25\text{ °C}</math></b>						
$R_{ON(peak)}$	ON resistance (peak)	$V_{is} = V_{CC}$ to $V_{EE}$				
		$V_{CC} = 2.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $I_{SW} = 100\text{ }\mu\text{A}$	[1] -	-	-	$\Omega$
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $I_{SW} = 1000\text{ }\mu\text{A}$	-	100	180	$\Omega$
		$V_{CC} = 6.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $I_{SW} = 1000\text{ }\mu\text{A}$	-	90	160	$\Omega$
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$ ; $I_{SW} = 1000\text{ }\mu\text{A}$	-	70	130	$\Omega$
$R_{ON(rail)}$	ON resistance (rail)	$V_{is} = V_{EE}$				
		$V_{CC} = 2.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $I_{SW} = 100\text{ }\mu\text{A}$	[1] -	150	-	$\Omega$
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $I_{SW} = 1000\text{ }\mu\text{A}$	-	80	140	$\Omega$
		$V_{CC} = 6.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $I_{SW} = 1000\text{ }\mu\text{A}$	-	70	120	$\Omega$
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$ ; $I_{SW} = 1000\text{ }\mu\text{A}$	-	60	105	$\Omega$
		$V_{is} = V_{CC}$				
		$V_{CC} = 2.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $I_{SW} = 100\text{ }\mu\text{A}$	[1] -	150	-	$\Omega$
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $I_{SW} = 1000\text{ }\mu\text{A}$	-	90	160	$\Omega$
		$V_{CC} = 6.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $I_{SW} = 1000\text{ }\mu\text{A}$	-	80	140	$\Omega$
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$ ; $I_{SW} = 1000\text{ }\mu\text{A}$	-	65	120	$\Omega$
$\Delta R_{ON}$	ON resistance mismatch between channels	$V_{is} = V_{CC}$ to $V_{EE}$				
		$V_{CC} = 2.0\text{ V}$ ; $V_{EE} = 0\text{ V}$	[1] -	-	-	$\Omega$
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	9	-	$\Omega$
		$V_{CC} = 6.0\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	8	-	$\Omega$
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	-	6	-	$\Omega$
<b><math>T_{amb} = -40\text{ °C to }+85\text{ °C}</math></b>						
$R_{ON(peak)}$	ON resistance (peak)	$V_{is} = V_{CC}$ to $V_{EE}$				
		$V_{CC} = 2.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $I_{SW} = 100\text{ }\mu\text{A}$	[1] -	-	-	$\Omega$
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $I_{SW} = 1000\text{ }\mu\text{A}$	-	-	225	$\Omega$
		$V_{CC} = 6.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $I_{SW} = 1000\text{ }\mu\text{A}$	-	-	200	$\Omega$
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$ ; $I_{SW} = 1000\text{ }\mu\text{A}$	-	-	165	$\Omega$



**Table 6.**  $R_{ON}$  resistance per switch for 74HC4051-Q100 and 74HCT4051-Q100 ...continued

$V_I = V_{IH}$  or  $V_{IL}$ ; for test circuit see [Figure 9](#).

$V_{is}$  is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

$V_{os}$  is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

For 74HC4051-Q100:  $V_{CC} - GND$  or  $V_{CC} - V_{EE} = 2.0\text{ V}$ ,  $4.5\text{ V}$ ,  $6.0\text{ V}$  and  $9.0\text{ V}$ .

For 74HCT4051-Q100:  $V_{CC} - GND = 4.5\text{ V}$  and  $5.5\text{ V}$ ,  $V_{CC} - V_{EE} = 2.0\text{ V}$ ,  $4.5\text{ V}$ ,  $6.0\text{ V}$  and  $9.0\text{ V}$ .

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
R <sub>ON(rail)</sub>	ON resistance (rail)	V <sub>is</sub> = V <sub>EE</sub>				
		V <sub>CC</sub> = 2.0 V; V <sub>EE</sub> = 0 V; I <sub>SW</sub> = 100 μA	[1]	-	-	Ω
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V; I <sub>SW</sub> = 1000 μA	-	-	175	Ω
		V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V; I <sub>SW</sub> = 1000 μA	-	-	150	Ω
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V; I <sub>SW</sub> = 1000 μA	-	-	130	Ω
		V <sub>is</sub> = V <sub>CC</sub>				
		V <sub>CC</sub> = 2.0 V; V <sub>EE</sub> = 0 V; I <sub>SW</sub> = 100 μA	[1]	-	-	Ω
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V; I <sub>SW</sub> = 1000 μA	-	-	200	Ω
		V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V; I <sub>SW</sub> = 1000 μA	-	-	175	Ω
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V; I <sub>SW</sub> = 1000 μA	-	-	150	Ω
T <sub>amb</sub> = -40 °C to +125 °C						
R <sub>ON(peak)</sub>	ON resistance (peak)	V <sub>is</sub> = V <sub>CC</sub> to V <sub>EE</sub>				
		V <sub>CC</sub> = 2.0 V; V <sub>EE</sub> = 0 V; I <sub>SW</sub> = 100 μA	[1]	-	-	Ω
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V; I <sub>SW</sub> = 1000 μA	-	-	270	Ω
		V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V; I <sub>SW</sub> = 1000 μA	-	-	240	Ω
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V; I <sub>SW</sub> = 1000 μA	-	-	195	Ω
R <sub>ON(rail)</sub>	ON resistance (rail)	V <sub>is</sub> = V <sub>EE</sub>				
		V <sub>CC</sub> = 2.0 V; V <sub>EE</sub> = 0 V; I <sub>SW</sub> = 100 μA	[1]	-	-	Ω
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V; I <sub>SW</sub> = 1000 μA	-	-	210	Ω
		V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V; I <sub>SW</sub> = 1000 μA	-	-	180	Ω
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V; I <sub>SW</sub> = 1000 μA	-	-	160	Ω
		V <sub>is</sub> = V <sub>CC</sub>				
		V <sub>CC</sub> = 2.0 V; V <sub>EE</sub> = 0 V; I <sub>SW</sub> = 100 μA	[1]	-	-	Ω
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V; I <sub>SW</sub> = 1000 μA	-	-	240	Ω
		V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V; I <sub>SW</sub> = 1000 μA	-	-	210	Ω
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V; I <sub>SW</sub> = 1000 μA	-	-	180	Ω

- [1] When supply voltages ( $V_{CC} - V_{EE}$ ) near  $2.0\text{ V}$  the analog switch ON resistance becomes extremely non-linear. When using a supply of  $2\text{ V}$ , it is recommended to use these devices only for transmitting digital signals.



**Table 7.** Static characteristics for 74HC4051-Q100 ...continued

Voltages are referenced to GND (ground = 0 V).

$V_{is}$  is the input voltage at pins Yn or Z, whichever is assigned as an input.

$V_{os}$  is the output voltage at pins Z or Yn, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I <sub>CC</sub>	supply current	V <sub>EE</sub> = 0 V; V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>is</sub> = V <sub>EE</sub> or V <sub>CC</sub> ; V <sub>os</sub> = V <sub>CC</sub> or V <sub>EE</sub>				
		V <sub>CC</sub> = 6.0 V	-	-	8.0	μA
		V <sub>CC</sub> = 10.0 V	-	-	16.0	μA
C <sub>I</sub>	input capacitance		-	3.5	-	pF
C <sub>sw</sub>	switch capacitance	independent pins Yn	-	5	-	pF
		common pins Z	-	25	-	pF
T <sub>amb</sub> = −40 °C to +85 °C						
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	-	-	V
		V <sub>CC</sub> = 4.5 V	3.15	-	-	V
		V <sub>CC</sub> = 6.0 V	4.2	-	-	V
		V <sub>CC</sub> = 9.0 V	6.3	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	-	0.5	V
		V <sub>CC</sub> = 4.5 V	-	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	-	1.8	V
		V <sub>CC</sub> = 9.0 V	-	-	2.7	V
I <sub>I</sub>	input leakage current	V <sub>EE</sub> = 0 V; V <sub>I</sub> = V <sub>CC</sub> or GND				
		V <sub>CC</sub> = 6.0 V	-	-	±1.0	μA
		V <sub>CC</sub> = 10.0 V	-	-	±2.0	μA
I <sub>S(OFF)</sub>	OFF-state leakage current	V <sub>CC</sub> = 10.0 V; V <sub>EE</sub> = 0 V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ;  V <sub>SW</sub>   = V <sub>CC</sub> − V <sub>EE</sub> ; see <a href="#">Figure 11</a>				
		per channel	-	-	±1.0	μA
		all channels	-	-	±4.0	μA
I <sub>S(ON)</sub>	ON-state leakage current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ;  V <sub>SW</sub>   = V <sub>CC</sub> − V <sub>EE</sub> ; V <sub>CC</sub> = 10.0 V; V <sub>EE</sub> = 0 V; see <a href="#">Figure 12</a>	-	-	±4.0	μA
I <sub>CC</sub>	supply current	V <sub>EE</sub> = 0 V; V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>is</sub> = V <sub>EE</sub> or V <sub>CC</sub> ; V <sub>os</sub> = V <sub>CC</sub> or V <sub>EE</sub>				
		V <sub>CC</sub> = 6.0 V	-	-	80.0	μA
		V <sub>CC</sub> = 10.0 V	-	-	160.0	μA
T <sub>amb</sub> = −40 °C to +125 °C						
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	-	-	V
		V <sub>CC</sub> = 4.5 V	3.15	-	-	V
		V <sub>CC</sub> = 6.0 V	4.2	-	-	V
		V <sub>CC</sub> = 9.0 V	6.3	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	-	0.5	V
		V <sub>CC</sub> = 4.5 V	-	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	-	1.8	V
		V <sub>CC</sub> = 9.0 V	-	-	2.7	V

**Table 7.** Static characteristics for 74HC4051-Q100 ...continued

Voltages are referenced to GND (ground = 0 V).

$V_{IS}$  is the input voltage at pins Yn or Z, whichever is assigned as an input.

$V_{OS}$  is the output voltage at pins Z or Yn, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$I_I$	input leakage current	$V_{EE} = 0\text{ V}$ ; $V_I = V_{CC}$ or GND				
		$V_{CC} = 6.0\text{ V}$	-	-	$\pm 1.0$	$\mu\text{A}$
		$V_{CC} = 10.0\text{ V}$	-	-	$\pm 2.0$	$\mu\text{A}$
$I_{S(OFF)}$	OFF-state leakage current	$V_{CC} = 10.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $ V_{SW}  = V_{CC} - V_{EE}$ ; see <a href="#">Figure 11</a>				
		per channel	-	-	$\pm 1.0$	$\mu\text{A}$
		all channels	-	-	$\pm 4.0$	$\mu\text{A}$
$I_{S(ON)}$	ON-state leakage current	$V_I = V_{IH}$ or $V_{IL}$ ; $ V_{SW}  = V_{CC} - V_{EE}$ ; $V_{CC} = 10.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; see <a href="#">Figure 12</a>	-	-	$\pm 4.0$	$\mu\text{A}$
$I_{CC}$	supply current	$V_{EE} = 0\text{ V}$ ; $V_I = V_{CC}$ or GND; $V_{IS} = V_{EE}$ or $V_{CC}$ ; $V_{OS} = V_{CC}$ or $V_{EE}$				
		$V_{CC} = 6.0\text{ V}$	-	-	160.0	$\mu\text{A}$
		$V_{CC} = 10.0\text{ V}$	-	-	320.0	$\mu\text{A}$

**Table 8.** Static characteristics for 74HCT4051-Q100

Voltages are referenced to GND (ground = 0 V).

$V_{IS}$  is the input voltage at pins Yn or Z, whichever is assigned as an input.

$V_{OS}$  is the output voltage at pins Z or Yn, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b><math>T_{amb} = 25\text{ }^{\circ}\text{C}</math></b>						
$V_{IH}$	HIGH-level input voltage	$V_{CC} = 4.5\text{ V}$ to $5.5\text{ V}$	2.0	1.6	-	V
$V_{IL}$	LOW-level input voltage	$V_{CC} = 4.5\text{ V}$ to $5.5\text{ V}$	-	1.2	0.8	V
$I_I$	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	-	$\pm 0.1$	$\mu\text{A}$
$I_{S(OFF)}$	OFF-state leakage current	$V_{CC} = 10.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $ V_{SW}  = V_{CC} - V_{EE}$ ; see <a href="#">Figure 11</a>				
		per channel	-	-	$\pm 0.1$	$\mu\text{A}$
		all channels	-	-	$\pm 0.4$	$\mu\text{A}$
$I_{S(ON)}$	ON-state leakage current	$V_{CC} = 10.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $ V_{SW}  = V_{CC} - V_{EE}$ ; see <a href="#">Figure 12</a>	-	-	$\pm 0.4$	$\mu\text{A}$
$I_{CC}$	supply current	$V_I = V_{CC}$ or GND; $V_{IS} = V_{EE}$ or $V_{CC}$ ; $V_{OS} = V_{CC}$ or $V_{EE}$				
		$V_{CC} = 5.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	-	8.0	$\mu\text{A}$
		$V_{CC} = 5.0\text{ V}$ ; $V_{EE} = -5.0\text{ V}$	-	-	16.0	$\mu\text{A}$
$\Delta I_{CC}$	additional supply current	per input; $V_I = V_{CC} - 2.1\text{ V}$ ; other inputs at $V_{CC}$ or GND; $V_{CC} = 4.5\text{ V}$ to $5.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	50	180	$\mu\text{A}$
$C_I$	input capacitance		-	3.5	-	pF
$C_{SW}$	switch capacitance	independent pins Yn	-	5	-	pF
		common pins Z	-	25	-	pF

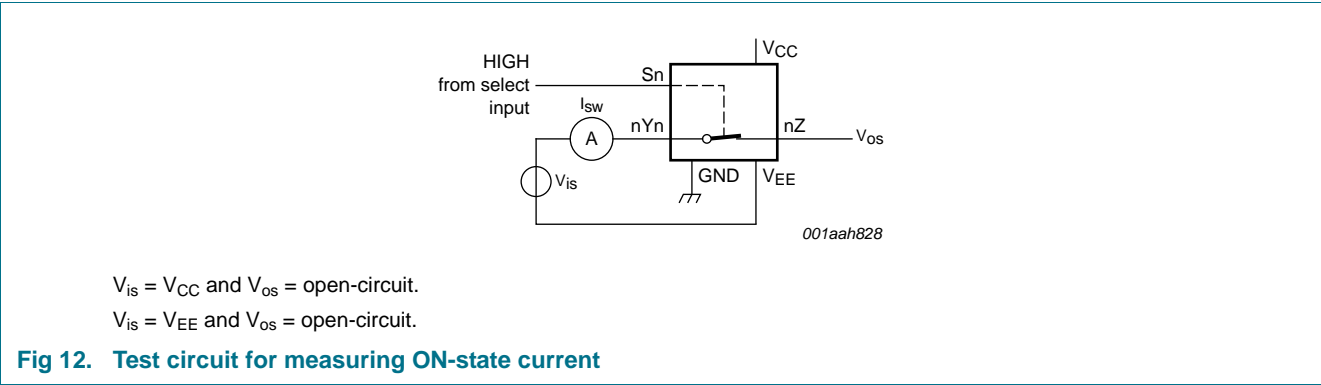
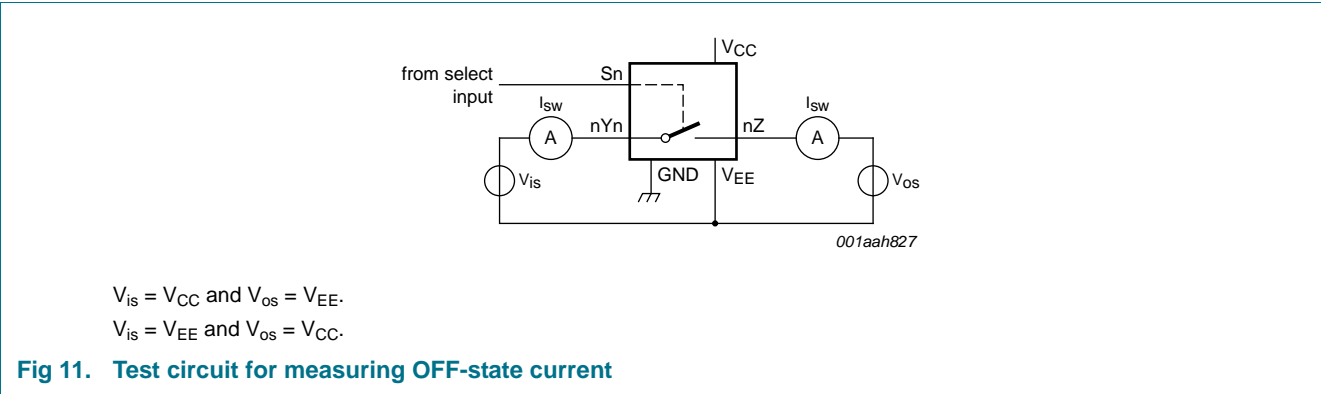
**Table 8.** Static characteristics for 74HCT4051-Q100 ...continued

Voltages are referenced to GND (ground = 0 V).

$V_{IS}$  is the input voltage at pins Yn or Z, whichever is assigned as an input.

$V_{OS}$  is the output voltage at pins Z or Yn, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b><math>T_{amb} = -40\text{ °C to }+85\text{ °C}</math></b>						
$V_{IH}$	HIGH-level input voltage	$V_{CC} = 4.5\text{ V to }5.5\text{ V}$	2.0	-	-	V
$V_{IL}$	LOW-level input voltage	$V_{CC} = 4.5\text{ V to }5.5\text{ V}$	-	-	0.8	V
$I_I$	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	-	$\pm 1.0$	$\mu\text{A}$
$I_{S(OFF)}$	OFF-state leakage current	$V_{CC} = 10.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $ V_{SW}  = V_{CC} - V_{EE}$ ; see <a href="#">Figure 11</a>				
		per channel	-	-	$\pm 1.0$	$\mu\text{A}$
		all channels	-	-	$\pm 4.0$	$\mu\text{A}$
$I_{S(ON)}$	ON-state leakage current	$V_{CC} = 10.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $ V_{SW}  = V_{CC} - V_{EE}$ ; see <a href="#">Figure 12</a>	-	-	$\pm 4.0$	$\mu\text{A}$
$I_{CC}$	supply current	$V_I = V_{CC}$ or GND; $V_{IS} = V_{EE}$ or $V_{CC}$ ; $V_{OS} = V_{CC}$ or $V_{EE}$				
		$V_{CC} = 5.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	-	80.0	$\mu\text{A}$
		$V_{CC} = 5.0\text{ V}$ ; $V_{EE} = -5.0\text{ V}$	-	-	160.0	$\mu\text{A}$
$\Delta I_{CC}$	additional supply current	per input; $V_I = V_{CC} - 2.1\text{ V}$ ; other inputs at $V_{CC}$ or GND; $V_{CC} = 4.5\text{ V to }5.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	-	225	$\mu\text{A}$
<b><math>T_{amb} = -40\text{ °C to }+125\text{ °C}</math></b>						
$V_{IH}$	HIGH-level input voltage	$V_{CC} = 4.5\text{ V to }5.5\text{ V}$	2.0	-	-	V
$V_{IL}$	LOW-level input voltage	$V_{CC} = 4.5\text{ V to }5.5\text{ V}$	-	-	0.8	V
$I_I$	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	-	$\pm 1.0$	$\mu\text{A}$
$I_{S(OFF)}$	OFF-state leakage current	$V_{CC} = 10.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $ V_{SW}  = V_{CC} - V_{EE}$ ; see <a href="#">Figure 11</a>				
		per channel	-	-	$\pm 1.0$	$\mu\text{A}$
		all channels	-	-	$\pm 4.0$	$\mu\text{A}$
$I_{S(ON)}$	ON-state leakage current	$V_{CC} = 10.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $ V_{SW}  = V_{CC} - V_{EE}$ ; see <a href="#">Figure 12</a>	-	-	$\pm 4.0$	$\mu\text{A}$
$I_{CC}$	supply current	$V_I = V_{CC}$ or GND; $V_{IS} = V_{EE}$ or $V_{CC}$ ; $V_{OS} = V_{CC}$ or $V_{EE}$				
		$V_{CC} = 5.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	-	160.0	$\mu\text{A}$
		$V_{CC} = 5.0\text{ V}$ ; $V_{EE} = -5.0\text{ V}$	-	-	320.0	$\mu\text{A}$
$\Delta I_{CC}$	additional supply current	per input; $V_I = V_{CC} - 2.1\text{ V}$ ; other inputs at $V_{CC}$ or GND; $V_{CC} = 4.5\text{ V to }5.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	-	245	$\mu\text{A}$



11. Dynamic characteristics

**Table 9. Dynamic characteristics for 74HC4051-Q100**  
 $GND = 0\text{ V}$ ;  $t_r = t_f = 6\text{ ns}$ ;  $C_L = 50\text{ pF}$ ; for test circuit see [Figure 15](#).  
 $V_{is}$  is the input voltage at a Yn or Z terminal, whichever is assigned as an input.  
 $V_{os}$  is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>T<sub>amb</sub> = 25 °C</b>						
t <sub>pd</sub>	propagation delay	V <sub>is</sub> to V <sub>os</sub> ; R <sub>L</sub> = ∞ Ω; see <a href="#">Figure 13</a>	[1]			
		V <sub>CC</sub> = 2.0 V; V <sub>EE</sub> = 0 V	-	14	60	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V	-	5	12	ns
		V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V	-	4	10	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V	-	4	8	ns

**Table 9.** Dynamic characteristics for 74HC4051-Q100 ...continued

$GND = 0\text{ V}$ ;  $t_r = t_f = 6\text{ ns}$ ;  $C_L = 50\text{ pF}$ ; for test circuit see [Figure 15](#).

$V_{is}$  is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

$V_{os}$  is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$t_{on}$	turn-on time	$\bar{E}$ to $V_{os}$ ; $R_L = \infty\ \Omega$ ; see <a href="#">Figure 14</a>	[2]			
		$V_{CC} = 2.0\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	72	345	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	29	69	ns
		$V_{CC} = 5.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $C_L = 15\text{ pF}$	-	22	-	ns
		$V_{CC} = 6.0\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	21	59	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	-	18	51	ns
		Sn to $V_{os}$ ; $R_L = \infty\ \Omega$ ; see <a href="#">Figure 14</a>	[2]			
		$V_{CC} = 2.0\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	66	345	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	28	69	ns
		$V_{CC} = 5.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $C_L = 15\text{ pF}$	-	20	-	ns
		$V_{CC} = 6.0\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	19	59	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	-	16	51	ns
$t_{off}$	turn-off time	$\bar{E}$ to $V_{os}$ ; $R_L = 1\text{ k}\Omega$ ; see <a href="#">Figure 14</a>	[3]			
		$V_{CC} = 2.0\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	58	290	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	31	58	ns
		$V_{CC} = 5.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $C_L = 15\text{ pF}$	-	18	-	ns
		$V_{CC} = 6.0\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	17	49	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	-	18	42	ns
		Sn to $V_{os}$ ; $R_L = 1\text{ k}\Omega$ ; see <a href="#">Figure 14</a>	[3]			
		$V_{CC} = 2.0\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	61	290	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	25	58	ns
		$V_{CC} = 5.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $C_L = 15\text{ pF}$	-	19	-	ns
		$V_{CC} = 6.0\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	18	49	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	-	18	42	ns
$C_{PD}$	power dissipation capacitance	per switch; $V_I = GND$ to $V_{CC}$	[4]	-	25	pF
<b><math>T_{amb} = -40\text{ }^{\circ}\text{C to }+85\text{ }^{\circ}\text{C}</math></b>						
$t_{pd}$	propagation delay	$V_{is}$ to $V_{os}$ ; $R_L = \infty\ \Omega$ ; see <a href="#">Figure 13</a>	[1]			
		$V_{CC} = 2.0\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	-	75	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	-	15	ns
		$V_{CC} = 6.0\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	-	13	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	-	-	10	ns

**Table 9.** Dynamic characteristics for 74HC4051-Q100 ...continued

$GND = 0\text{ V}$ ;  $t_r = t_f = 6\text{ ns}$ ;  $C_L = 50\text{ pF}$ ; for test circuit see [Figure 15](#).

$V_{is}$  is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

$V_{os}$  is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
t <sub>on</sub>	turn-on time	$\overline{E}$ to V <sub>os</sub> ; R <sub>L</sub> = ∞ Ω; see <a href="#">Figure 14</a>	[2]			
		V <sub>CC</sub> = 2.0 V; V <sub>EE</sub> = 0 V	-	-	430	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V	-	-	86	ns
		V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V	-	-	73	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V	-	-	64	ns
		Sn to V <sub>os</sub> ; R <sub>L</sub> = ∞ Ω; see <a href="#">Figure 14</a>	[2]			
		V <sub>CC</sub> = 2.0 V; V <sub>EE</sub> = 0 V	-	-	430	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V	-	-	86	ns
		V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V	-	-	73	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V	-	-	64	ns
t <sub>off</sub>	turn-off time	$\overline{E}$ to V <sub>os</sub> ; R <sub>L</sub> = 1 kΩ; see <a href="#">Figure 14</a>	[3]			
		V <sub>CC</sub> = 2.0 V; V <sub>EE</sub> = 0 V	-	-	365	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V	-	-	73	ns
		V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V	-	-	62	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V	-	-	53	ns
		Sn to V <sub>os</sub> ; R <sub>L</sub> = 1 kΩ; see <a href="#">Figure 14</a>	[3]			
		V <sub>CC</sub> = 2.0 V; V <sub>EE</sub> = 0 V	-	-	365	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V	-	-	73	ns
		V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V	-	-	62	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V	-	-	53	ns
T <sub>amb</sub> = -40 °C to +125 °C						
t <sub>pd</sub>	propagation delay	V <sub>is</sub> to V <sub>os</sub> ; R <sub>L</sub> = ∞ Ω; see <a href="#">Figure 13</a>	[1]			
		V <sub>CC</sub> = 2.0 V; V <sub>EE</sub> = 0 V	-	-	90	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V	-	-	18	ns
		V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V	-	-	15	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V	-	-	12	ns
t <sub>on</sub>	turn-on time	$\overline{E}$ to V <sub>os</sub> ; R <sub>L</sub> = ∞ Ω; see <a href="#">Figure 14</a>	[2]			
		V <sub>CC</sub> = 2.0 V; V <sub>EE</sub> = 0 V	-	-	520	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V	-	-	104	ns
		V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V	-	-	88	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V	-	-	77	ns
		Sn to V <sub>os</sub> ; R <sub>L</sub> = ∞ Ω; see <a href="#">Figure 14</a>	[2]			
		V <sub>CC</sub> = 2.0 V; V <sub>EE</sub> = 0 V	-	-	520	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V	-	-	104	ns
		V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V	-	-	88	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V	-	-	77	ns



**Table 9. Dynamic characteristics for 74HC4051-Q100 ...continued**

$GND = 0\text{ V}$ ;  $t_r = t_f = 6\text{ ns}$ ;  $C_L = 50\text{ pF}$ ; for test circuit see [Figure 15](#).

$V_{is}$  is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

$V_{os}$  is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$t_{off}$	turn-off time	$\bar{E}$ to $V_{os}$ ; $R_L = 1\text{ k}\Omega$ ; see <a href="#">Figure 14</a> <a href="#">[3]</a>				
		$V_{CC} = 2.0\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	-	435	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	-	87	ns
		$V_{CC} = 6.0\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	-	74	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	-	-	72	ns
		Sn to $V_{os}$ ; $R_L = 1\text{ k}\Omega$ ; see <a href="#">Figure 14</a> <a href="#">[3]</a>				
		$V_{CC} = 2.0\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	-	435	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	-	87	ns
		$V_{CC} = 6.0\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	-	74	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	-	-	72	ns

[1]  $t_{pd}$  is the same as  $t_{PHL}$  and  $t_{PLH}$ .

[2]  $t_{on}$  is the same as  $t_{pZH}$  and  $t_{pZL}$ .

[3]  $t_{off}$  is the same as  $t_{pHZ}$  and  $t_{pLZ}$ .

[4]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ).

$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma\{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\}$  where:

$f_i$  = input frequency in MHz;

$f_o$  = output frequency in MHz;

$N$  = number of inputs switching;

$\Sigma\{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\}$  = sum of outputs;

$C_L$  = output load capacitance in pF;

$C_{sw}$  = switch capacitance in pF;

$V_{CC}$  = supply voltage in V.

**Table 10. Dynamic characteristics for 74HCT4051-Q100**

$GND = 0\text{ V}$ ;  $t_r = t_f = 6\text{ ns}$ ;  $C_L = 50\text{ pF}$ ; for test circuit see [Figure 15](#).

$V_{is}$  is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

$V_{os}$  is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b><math>T_{amb} = 25\text{ }^\circ\text{C}</math></b>						
$t_{pd}$	propagation delay	$V_{is}$ to $V_{os}$ ; $R_L = \infty\text{ }\Omega$ ; see <a href="#">Figure 13</a> <a href="#">[1]</a>				
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	5	12	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	-	4	8	ns
$t_{on}$	turn-on time	$\bar{E}$ to $V_{os}$ ; $R_L = 1\text{ k}\Omega$ ; see <a href="#">Figure 14</a> <a href="#">[2]</a>				
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	26	55	ns
		$V_{CC} = 5.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $C_L = 15\text{ pF}$	-	22	-	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	-	16	39	ns
		Sn to $V_{os}$ ; $R_L = 1\text{ k}\Omega$ ; see <a href="#">Figure 14</a> <a href="#">[2]</a>				
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	28	55	ns
		$V_{CC} = 5.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $C_L = 15\text{ pF}$	-	24	-	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	-	16	39	ns

**Table 10. Dynamic characteristics for 74HCT4051-Q100 ...continued**

$GND = 0\text{ V}$ ;  $t_r = t_f = 6\text{ ns}$ ;  $C_L = 50\text{ pF}$ ; for test circuit see [Figure 15](#).

$V_{is}$  is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

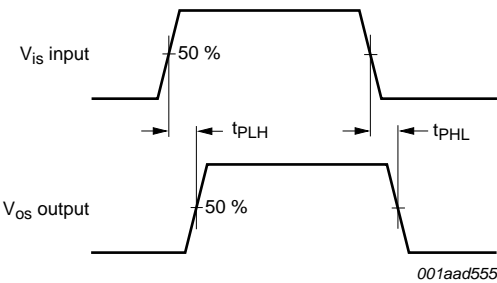
$V_{os}$  is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$t_{off}$	turn-off time	$\overline{E}$ to $V_{os}$ ; $R_L = 1\text{ k}\Omega$ ; see <a href="#">Figure 14</a> <a href="#">[3]</a>				
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	19	45	ns
		$V_{CC} = 5.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $C_L = 15\text{ pF}$	-	16	-	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	-	16	32	ns
		Sn to $V_{os}$ ; $R_L = 1\text{ k}\Omega$ ; see <a href="#">Figure 14</a> <a href="#">[3]</a>				
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	23	45	ns
		$V_{CC} = 5.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $C_L = 15\text{ pF}$	-	20	-	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	-	16	32	ns
$C_{PD}$	power dissipation capacitance	per switch; $V_I = \text{GND}$ to $V_{CC} - 1.5\text{ V}$ <a href="#">[4]</a>	-	25	-	pF
<b><math>T_{amb} = -40\text{ }^{\circ}\text{C}</math> to <math>+85\text{ }^{\circ}\text{C}</math></b>						
$t_{pd}$	propagation delay	$V_{is}$ to $V_{os}$ ; $R_L = \infty\text{ }\Omega$ ; see <a href="#">Figure 13</a> <a href="#">[1]</a>				
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	-	15	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	-	-	10	ns
$t_{on}$	turn-on time	$\overline{E}$ to $V_{os}$ ; $R_L = 1\text{ k}\Omega$ ; see <a href="#">Figure 14</a> <a href="#">[2]</a>				
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	-	69	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	-	-	49	ns
		Sn to $V_{os}$ ; $R_L = 1\text{ k}\Omega$ ; see <a href="#">Figure 14</a> <a href="#">[2]</a>				
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	-	69	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	-	-	49	ns
$t_{off}$	turn-off time	$\overline{E}$ to $V_{os}$ ; $R_L = 1\text{ k}\Omega$ ; see <a href="#">Figure 14</a> <a href="#">[3]</a>				
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	-	56	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	-	-	40	ns
		Sn to $V_{os}$ ; $R_L = 1\text{ k}\Omega$ ; see <a href="#">Figure 14</a> <a href="#">[3]</a>				
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	-	56	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	-	-	40	ns
<b><math>T_{amb} = -40\text{ }^{\circ}\text{C}</math> to <math>+125\text{ }^{\circ}\text{C}</math></b>						
$t_{pd}$	propagation delay	$V_{is}$ to $V_{os}$ ; $R_L = \infty\text{ }\Omega$ ; see <a href="#">Figure 13</a> <a href="#">[1]</a>				
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	-	18	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	-	-	12	ns
$t_{on}$	turn-on time	$\overline{E}$ to $V_{os}$ ; $R_L = 1\text{ k}\Omega$ ; see <a href="#">Figure 14</a> <a href="#">[2]</a>				
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	-	83	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	-	-	59	ns
		Sn to $V_{os}$ ; $R_L = 1\text{ k}\Omega$ ; see <a href="#">Figure 14</a> <a href="#">[2]</a>				
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	-	83	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	-	-	59	ns

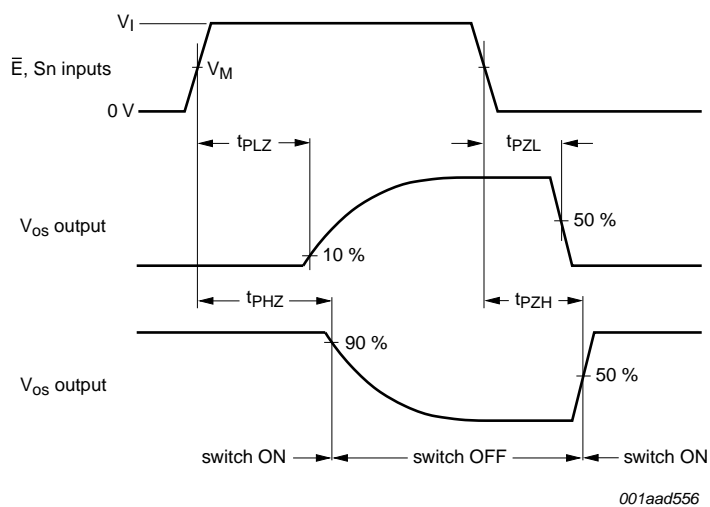
**Table 10. Dynamic characteristics for 74HCT4051-Q100 ...continued**  
*GND = 0 V;  $t_r = t_f = 6\text{ ns}$ ;  $C_L = 50\text{ pF}$ ; for test circuit see [Figure 15](#).  
 $V_{is}$  is the input voltage at a Yn or Z terminal, whichever is assigned as an input.  
 $V_{os}$  is the output voltage at a Yn or Z terminal, whichever is assigned as an output.*

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$t_{off}$	turn-off time	$\overline{E}$ to $V_{os}$ ; $R_L = 1\text{ k}\Omega$ ; see <a href="#">Figure 14</a>	[3]			
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	-	68	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	-	-	48	ns
		$S_n$ to $V_{os}$ ; $R_L = 1\text{ k}\Omega$ ; see <a href="#">Figure 14</a>	[3]			
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	-	68	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	-	-	48	ns

- [1]  $t_{pd}$  is the same as  $t_{pHL}$  and  $t_{PLH}$ .  
[2]  $t_{on}$  is the same as  $t_{pZH}$  and  $t_{pZL}$ .  
[3]  $t_{off}$  is the same as  $t_{pHZ}$  and  $t_{pLZ}$ .  
[4]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ).  
 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma\{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\}$  where:  
 $f_i$  = input frequency in MHz;  
 $f_o$  = output frequency in MHz;  
 $N$  = number of inputs switching;  
 $\Sigma\{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\}$  = sum of outputs;  
 $C_L$  = output load capacitance in pF;  
 $C_{sw}$  = switch capacitance in pF;  
 $V_{CC}$  = supply voltage in V.



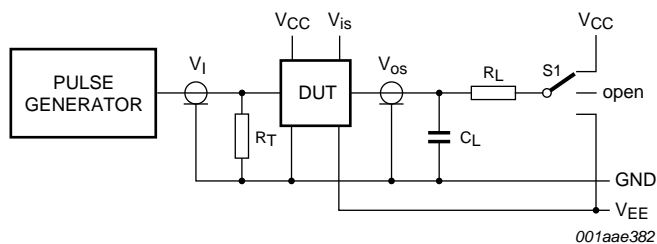
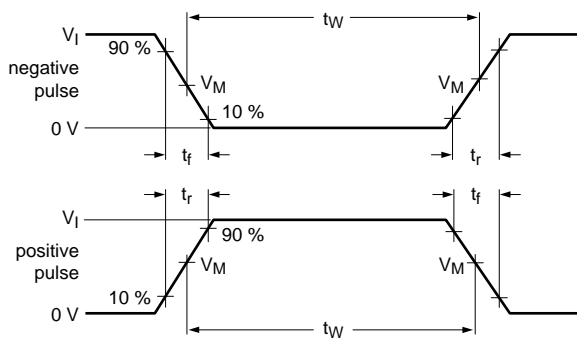
**Fig 13. Input ( $V_{is}$ ) to output ( $V_{os}$ ) propagation delays**



For 74HC4051-Q100:  $V_M = 0.5 \times V_{CC}$ .

For 74HCT4051-Q100:  $V_M = 1.3 \text{ V}$ .

**Fig 14. Turn-on and turn-off times**



Definitions for test circuit; see [Table 11](#):

$R_T$  = termination resistance should be equal to the output impedance  $Z_o$  of the pulse generator.

$C_L$  = load capacitance including jig and probe capacitance.

$R_L$  = load resistance.

S1 = Test selection switch.

**Fig 15. Test circuit for measuring AC performance**

Table 11. Test data

Test	Input				Load		S1 position
	V <sub>I</sub>	V <sub>is</sub>	t <sub>r</sub> , t <sub>f</sub>		C <sub>L</sub>	R <sub>L</sub>	
			at f <sub>max</sub>	other <sup>[1]</sup>			
t <sub>PHL</sub> , t <sub>PLH</sub>	[2]	pulse	< 2 ns	6 ns	50 pF	1 kΩ	open
t <sub>PZH</sub> , t <sub>PHZ</sub>	[2]	V <sub>CC</sub>	< 2 ns	6 ns	50 pF	1 kΩ	V <sub>EE</sub>
t <sub>PZL</sub> , t <sub>PLZ</sub>	[2]	V <sub>EE</sub>	< 2 ns	6 ns	50 pF	1 kΩ	V <sub>CC</sub>

[1] t<sub>r</sub> = t<sub>f</sub> = 6 ns; when measuring f<sub>max</sub>, there is no constraint to t<sub>r</sub> and t<sub>f</sub> with 50 % duty factor.

[2] V<sub>I</sub> values:  
a) For 74HC4051-Q100: V<sub>I</sub> = V<sub>CC</sub>  
b) For 74HCT4051-Q100: V<sub>I</sub> = 3 V

## 11.1 Additional dynamic characteristics

**Table 12. Additional dynamic characteristics**

Recommended conditions and typical values;  $GND = 0\text{ V}$ ;  $T_{amb} = 25\text{ }^{\circ}\text{C}$ ;  $C_L = 50\text{ pF}$ .

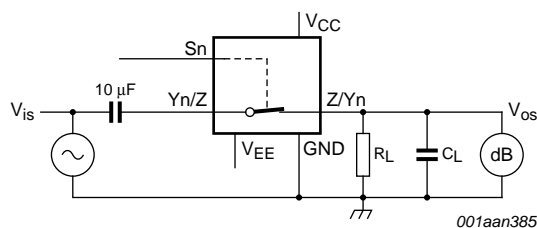
$V_{is}$  is the input voltage at pins  $nYn$  or  $nZ$ , whichever is assigned as an input.

$V_{os}$  is the output voltage at pins  $nYn$  or  $nZ$ , whichever is assigned as an output.

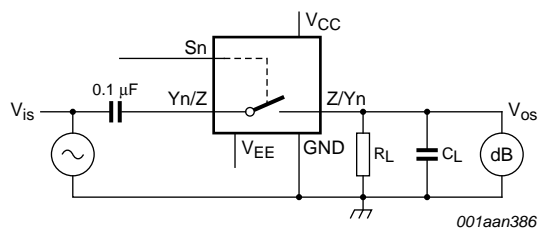
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$d_{sin}$	sine-wave distortion	$f_i = 1\text{ kHz}$ ; $R_L = 10\text{ k}\Omega$ ; see <a href="#">Figure 16</a>				
		$V_{is} = 4.0\text{ V (p-p)}$ ; $V_{CC} = 2.25\text{ V}$ ; $V_{EE} = -2.25\text{ V}$	-	0.04	-	%
		$V_{is} = 8.0\text{ V (p-p)}$ ; $V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	-	0.02	-	%
		$f_i = 10\text{ kHz}$ ; $R_L = 10\text{ k}\Omega$ ; see <a href="#">Figure 16</a>				
		$V_{is} = 4.0\text{ V (p-p)}$ ; $V_{CC} = 2.25\text{ V}$ ; $V_{EE} = -2.25\text{ V}$	-	0.12	-	%
		$V_{is} = 8.0\text{ V (p-p)}$ ; $V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	-	0.06	-	%
$\alpha_{iso}$	isolation (OFF-state)	$R_L = 600\text{ }\Omega$ ; $f_i = 1\text{ MHz}$ ; see <a href="#">Figure 17</a>				
		$V_{CC} = 2.25\text{ V}$ ; $V_{EE} = -2.25\text{ V}$	[1]	-	-50	dB
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	[1]	-	-50	dB
$V_{ct}$	crosstalk voltage	peak-to-peak value; between control and any switch; $R_L = 600\text{ }\Omega$ ; $f_i = 1\text{ MHz}$ ; $\bar{E}$ or $S_n$ square wave between $V_{CC}$ and $GND$ ; $t_r = t_f = 6\text{ ns}$ ; see <a href="#">Figure 18</a>				
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	110	-	mV
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	-	220	-	mV
$f_{(-3dB)}$	-3 dB frequency response	$R_L = 50\text{ }\Omega$ ; see <a href="#">Figure 19</a>				
		$V_{CC} = 2.25\text{ V}$ ; $V_{EE} = -2.25\text{ V}$	[2]	-	170	MHz
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	[2]	-	180	MHz

[1] Adjust input voltage  $V_{is}$  to 0 dBm level (0 dBm = 1 mW into 600  $\Omega$ ).

[2] Adjust input voltage  $V_{is}$  to 0 dBm level at  $V_{os}$  for 1 MHz (0 dBm = 1 mW into 50  $\Omega$ ).

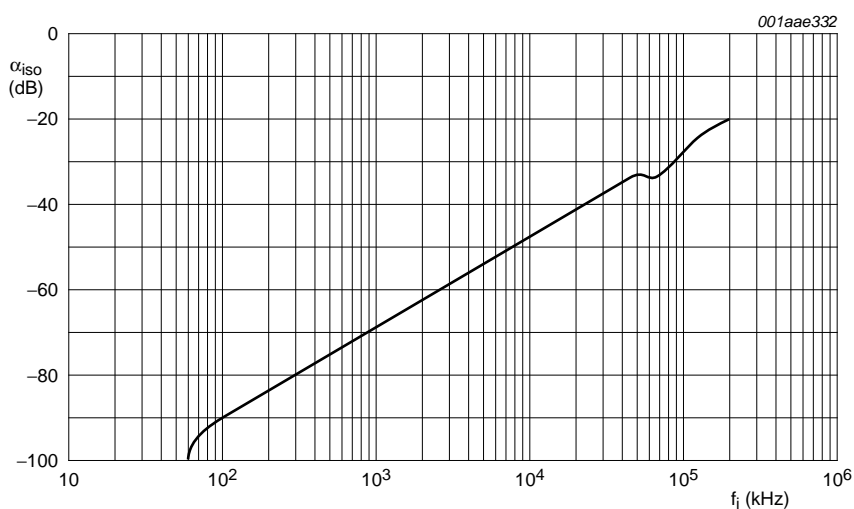


**Fig 16. Test circuit for measuring sine-wave distortion**



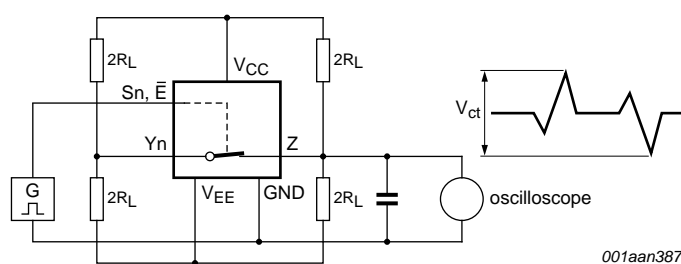
$V_{CC} = 4.5 \text{ V}$ ;  $GND = 0 \text{ V}$ ;  $V_{EE} = -4.5 \text{ V}$ ;  $R_L = 600 \Omega$ ;  $R_S = 1 \text{ k}\Omega$ .

a. Test circuit

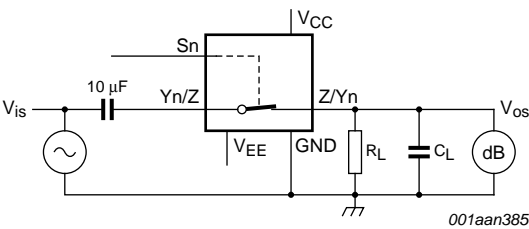


b. Isolation (OFF-state) as a function of frequency

**Fig 17. Test circuit for measuring isolation (OFF-state)**

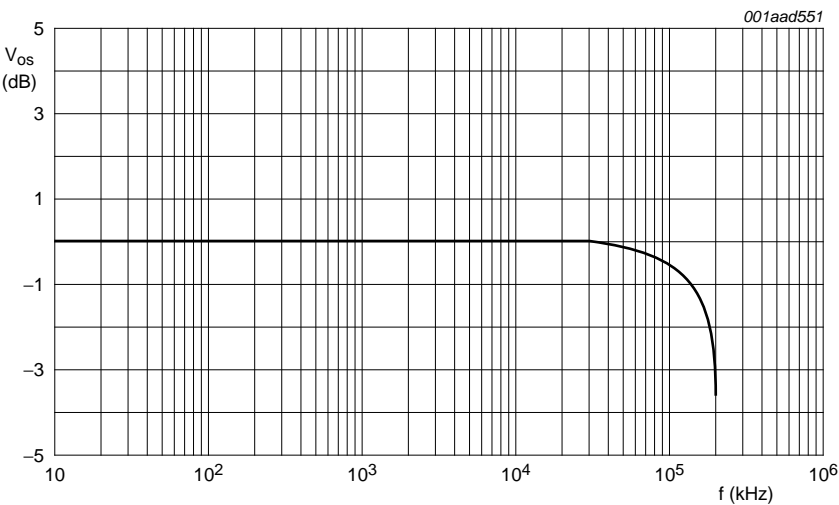


**Fig 18. Test circuit for measuring crosstalk between control input and any switch**



$V_{CC} = 4.5\text{ V}$ ;  $GND = 0\text{ V}$ ;  $V_{EE} = -4.5\text{ V}$ ;  $R_L = 50\text{ }\Omega$ ;  $R_S = 1\text{ k}\Omega$ .

a. Test circuit



b. Typical frequency response

Fig 19. Test circuit for frequency response



12. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mmSOT109-1

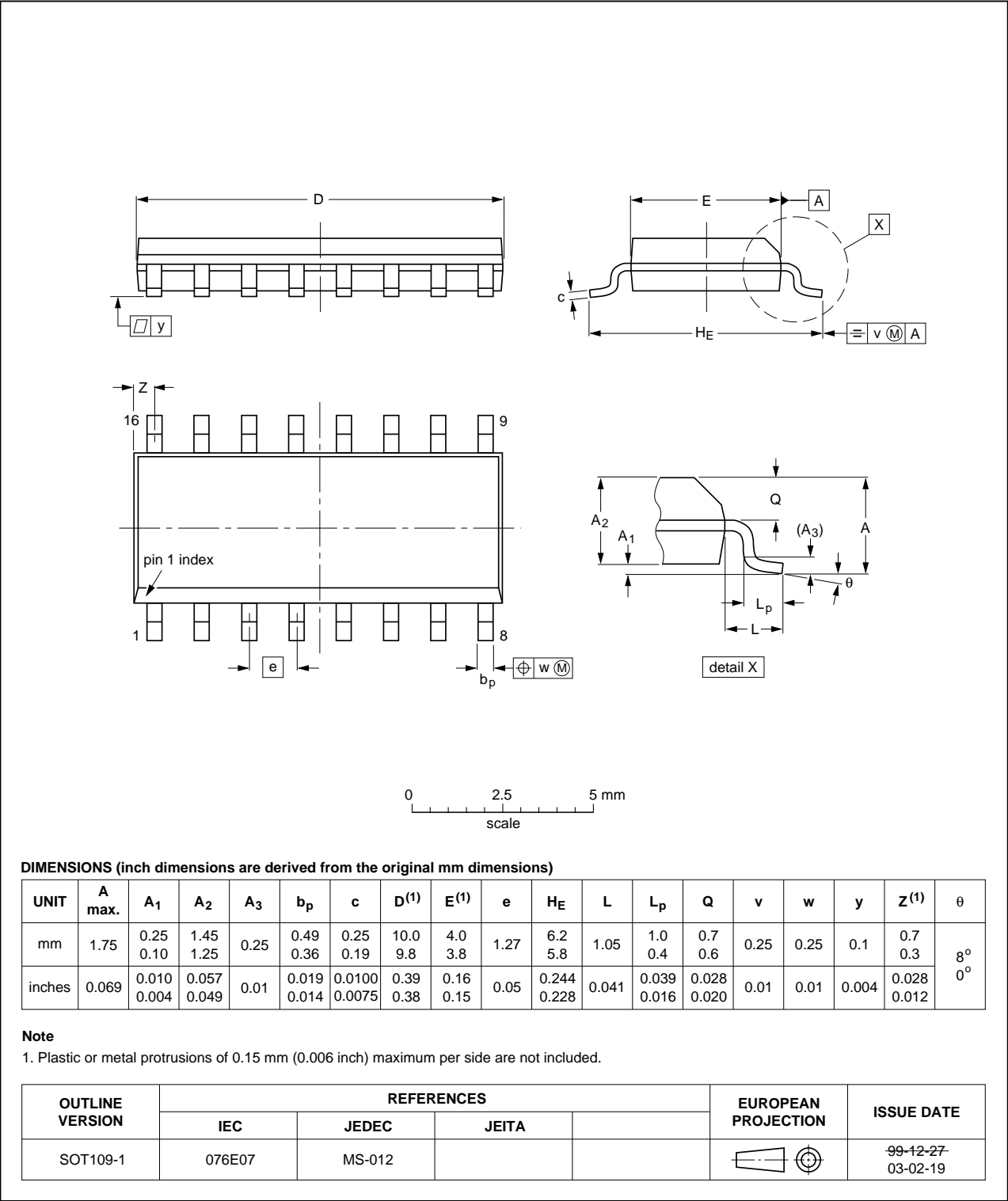


Fig 20. Package outline SOT109-1 (SO16)

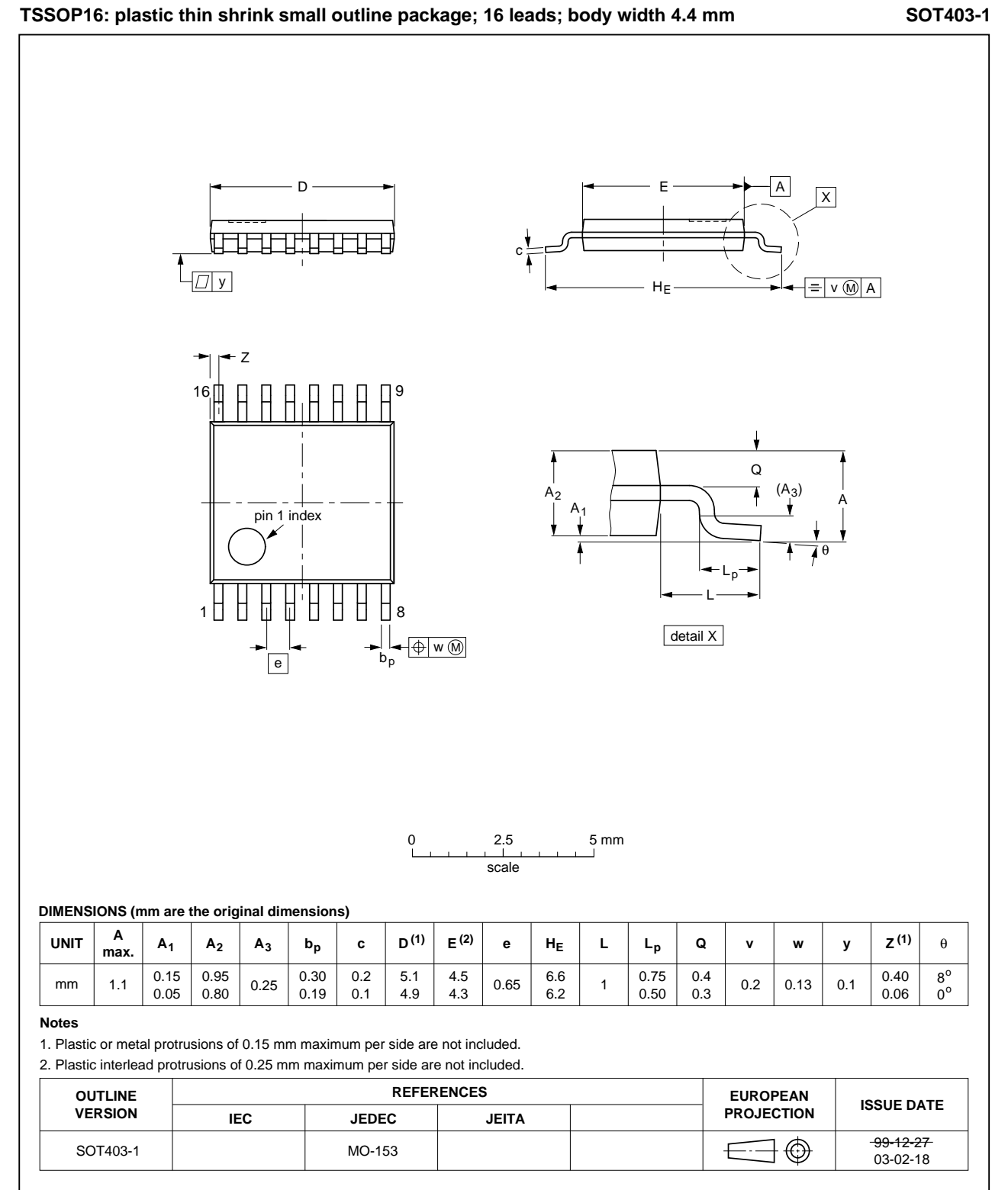


Fig 21. Package outline SOT403-1 (TSSOP16)

DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads;  
16 terminals; body 2.5 x 3.5 x 0.85 mm

SOT763-1

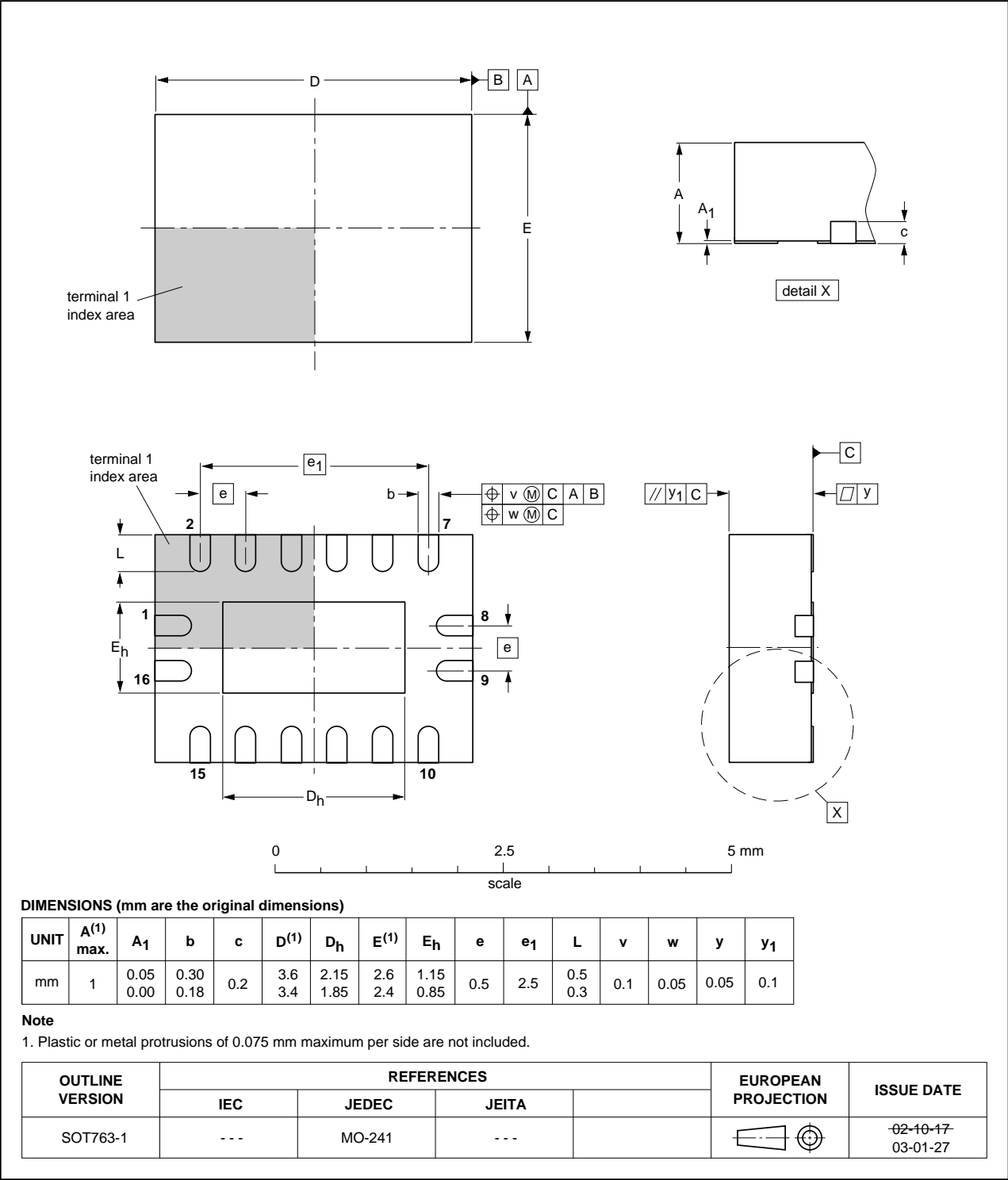


Fig 22. Package outline SOT763-1 (DHVQFN16)

## 13. Abbreviations

Table 13. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic
MIL	Military

## 14. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT4051_Q100 v.2	20121008	Product data sheet	-	74HC_HCT4051_Q100 v.1
Modifications:				
• CDM added to features.				
74HC_HCT4051_Q100 v.1	20120709	Product data sheet	-	-

## 15. Legal information

### 15.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

### 15.2 Definitions

**Draft** — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

**Short data sheet** — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

**Product specification** — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

### 15.3 Disclaimers

**Limited warranty and liability** — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. NXP Semiconductors takes no responsibility for the content in this document if provided by an information source outside of NXP Semiconductors.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

**Right to make changes** — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

**Suitability for use in automotive applications** — This NXP Semiconductors product has been qualified for use in automotive applications. Unless otherwise agreed in writing, the product is not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors and its suppliers accept no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

**Limiting values** — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

**Terms and conditions of commercial sale** — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at <http://www.nxp.com/profile/terms>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

**No offer to sell or license** — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

**Export control** — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

**Translations** — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

## 15.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

## 16. Contact information

---

For more information, please visit: <http://www.nxp.com>

For sales office addresses, please send an email to: [salesaddresses@nxp.com](mailto:salesaddresses@nxp.com)

## 17. Contents

---

<b>1</b>	<b>General description</b> .....	<b>1</b>
<b>2</b>	<b>Features and benefits</b> .....	<b>1</b>
<b>3</b>	<b>Applications</b> .....	<b>2</b>
<b>4</b>	<b>Ordering information</b> .....	<b>2</b>
<b>5</b>	<b>Functional diagram</b> .....	<b>3</b>
<b>6</b>	<b>Pinning information</b> .....	<b>5</b>
6.1	Pinning .....	5
6.2	Pin description .....	5
<b>7</b>	<b>Functional description</b> .....	<b>6</b>
7.1	Function table .....	6
<b>8</b>	<b>Limiting values</b> .....	<b>6</b>
<b>9</b>	<b>Recommended operating conditions</b> .....	<b>7</b>
<b>10</b>	<b>Static characteristics</b> .....	<b>8</b>
<b>11</b>	<b>Dynamic characteristics</b> .....	<b>14</b>
11.1	Additional dynamic characteristics .....	22
<b>12</b>	<b>Package outline</b> .....	<b>25</b>
<b>13</b>	<b>Abbreviations</b> .....	<b>28</b>
<b>14</b>	<b>Revision history</b> .....	<b>28</b>
<b>15</b>	<b>Legal information</b> .....	<b>29</b>
15.1	Data sheet status .....	29
15.2	Definitions .....	29
15.3	Disclaimers .....	29
15.4	Trademarks .....	30
<b>16</b>	<b>Contact information</b> .....	<b>30</b>
<b>17</b>	<b>Contents</b> .....	<b>31</b>

---

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

---

© NXP B.V. 2012.

All rights reserved.

For more information, please visit: <http://www.nxp.com>

For sales office addresses, please send an email to: [salesaddresses@nxp.com](mailto:salesaddresses@nxp.com)

Date of release: 8 October 2012

Document identifier: 74HC\_HCT4051\_Q100